

DATASHEET

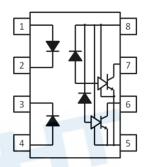
8 PIN DIP HIGH SPEED 10MBit/s LOGIC GATE PHOTOCOUPLER EL263X series



Features

- High speed 10Mbit/s
- 10kV/µs min. common mode transient immunity (EL2631)
- Guaranteed performance from -40 to 85°C
- · Logic gate output
- High isolation voltage between input and output (Viso=5000 Vrms)
- Pb free and RoHS compliant.
- UL and cUL approved(No. E214129)
- VDE approved (No. 132249)
- SEMKO approved
- NEMKO approved
- DEMKO approved
- FIMKO approved

Schematic



A 0.1µF bypass capacitor must be connected between pins 8 and 5 *3

Pin Configuration

- 1. Anode
- 2. Cathode
- 3. Cathode
- 4. Anode
- 5. Gnd
- 6. V_{out 2}
- 7. Vout 1
- 8. Vcc

Description

The EL2630 and EL2631 are consists of an infrared emitting diode optically coupled to a high speed integrated photo detector logic gate with a strobable output. It is packaged in a 8-pin DIP package and available in wide-lead spacing and SMD options.

Applications

- Ground loop elimination
- LSTTL to TTL, LSTTL or 5 volt CMOS
- · Line receiver, data transmission
- Data multiplexing
- Switching power supplies
- Pulse transformer replacement
- Computer peripheral interface
- High speed logic ground isolation

Truth Table (Positive Logic)

Input	Output
Н	L
L	Н



Absolute Maximum Ratings (TA=25°C)

	Parameter	Symbol	Rating	Unit
	Forward current	I _F	20	mA
Input	Reverse voltage	V_{R}	5	V
	Power dissipation	P _D	40	mW
	Power dissipation	Pc	60	mW
0	Output current	lo	50	mA
Output	Output voltage	Vo	7.0	V
	Supply voltage	Vcc	7.0	V
Output Po	ower Dissipation	Po	85	mW
Isolation voltage *1		V _{ISO}	5000	Vrms
Operating temperature		T _{OPR}	-40~+100	°C
Storage temperature		T _{STG}	-55~+125	°C
Soldering	temperature *2	T _{SOL}	260	°C

Notes:

^{*1} AC for 1 minute, R.H.= $40 \sim 60\%$ R.H. In this test, pins 1, 2, 3 & 4 are shorted together, and pins 5, 6, 7 & 8 are shorted together.

^{*2} For 10 seconds.



Electrical Characteristics (T_A =-40 to 85°C unless specified otherwise)

Input

Parameter	Symbol	Min.	Тур.*	Max.	Unit	Condition
Forward voltage	V_{F}	-	1.4	1.8	V	$I_F = 10 \text{mA}, T_A = 25 ^{\circ}\text{C}$
Reverse voltage	V_{R}	5.0	-	-	V	I _R = 10μA
Temperature coefficient of forward voltage	$\Delta V_F / \Delta T_A$	-	-1.8	-	mV/°C	I _F =10mA
Input capacitance	C _{IN}	-	60	-	pF	V _F =0, f=1MHz

Output

Parameter	Symbol	Min	Тур.*	Max.	Unit	Condition
High level supply current	Іссн	-	12.5	18	mA	I _F =0mA, V _{CC} =5.5V
Low level supply current	Iccl	-	14.5	21	mA	I _F =10mA, V _{CC} =5.5V

Transfer Characteristics (T_A =-40 to 85°C unless specified otherwise)

Parameter	Symbol	Min	Тур.	Max.	Unit	Condition
HIGH Level Output Current	Іон		2.1	100	μΑ	V _{CC} =5.5V, V _O =5.5V, I _F =250µA
LOW Level Output Current	Vol	-	0.35	0.6	V	$V_{CC} = 5.5V$, $I_F=5mA$, $I_{CL}=13mA$
Input Threshold Current	IFT	-	2.5	5	mA	V_{CC} = 5.5V, V_{O} =0.6V, I_{OL} =13mA

Switching Characteristics (T_A =-40 to 85°C, V_{CC}=5V, I_F=7.5mA unless specified otherwise)

Parameter	Symbol	Min	Тур.	Max.	Unit	Condition
Propagation delay time to output High level*4 (Fig.12)	T_PLH	-	35	100	ns	C_L = 15pF, R_L =350 Ω , T_A =25°C
Propagation delay time to output Low level*5 (Fig.12)	T_{PHL}	-	40	100	ns	C_L = 15pF, R_L =350 Ω , T_A =25°C
Pulse width distortion	$ T_{PHL}-T_{PLH} $	-	5	35	ns	$C_L = 15pF, R_L = 350\Omega$
Output rise time*6 (Fig.12)	tr	-	40	-	ns	C _L = 15pF, R _L =350Ω
Output fall time* ⁷ (Fig.12)	t _f	-	10	-	ns	$C_L = 15pF, R_L=350\Omega$



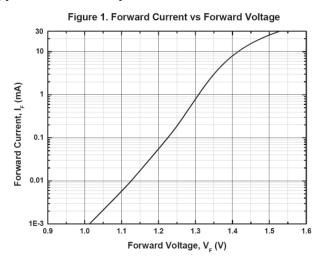
Switching Characteristics (T_A =-40 to 85°C, V_{CC}=5V, I_F=7.5mA unless specified otherwise)

Parame	eter	Symbol	Min	Тур.	Max.	Unit	Condition
Mode Transient ——— Immunity at	EL2630	CM	5,000	-	-	· V/µS	$\begin{split} I_F &= 0 mA \;,\; V_{CM} \!\!=\! 1 K V_{\text{p-p}}, \\ V_{OH} \!\!=\! 2.0 V,\; R_L \!\!=\! 350 \Omega, \\ T_A \!\!=\! 25^{\circ} \! C(\text{Fig.13}) \end{split}$
	EL2631	- CM _H	10,000	20,000	-		$I_F = 0mA$, $V_{CM}=1KV_{p-p}$, $V_{OH}=2.0V$, $R_L=350\Omega$, $T_A=25^{\circ}C(Fig.13)$
Common Mode Transient	EL2630	- CML	5,000	-	-	V/u.S	$I_F = 7.5 \text{mA}, V_{CM} = 1 \text{KV}_{p-p},$ $V_{OL} = 0.8 \text{V}, R_L = 350 \Omega,$ $T_A = 25 ^{\circ} \text{C(Fig.13)}$
Immunity at Logic Low *9	EL2631	- CIVIL	10,000	20,000	-	V/µS	$I_F = 7.5 \text{mA}, V_{CM} = 1 \text{KV}_{p-p},$ $V_{OL} = 0.8 \text{V}, R_L = 350 \Omega,$ $T_A = 25 \text{°C(Fig.13)}$





Typical Electro-Optical Characteristics Curves



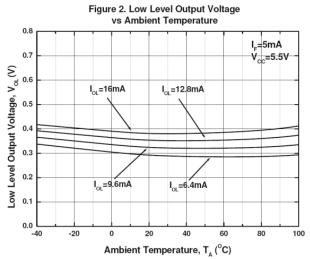
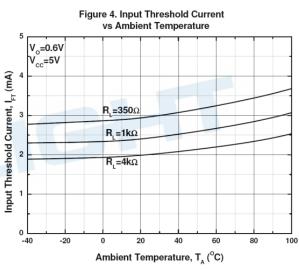
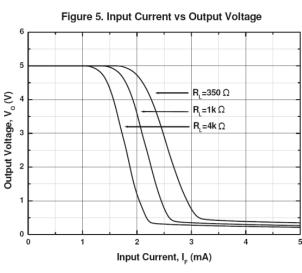
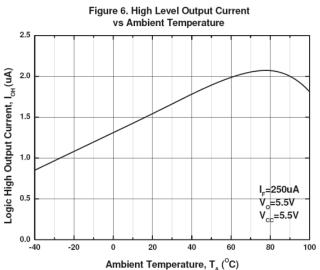


Figure 3. Low Level Output Current vs Ambient Temperature 75 V_{cc}=5V 70 V₀₁=0.6V Low Level Output Current, IoL (mA) 65 60 55 I_F=15mA 50 45 I_=10mA 40 35 30 25 20 15 10 -20 20 100 -40 Ambient Temperature, T_A (°C)









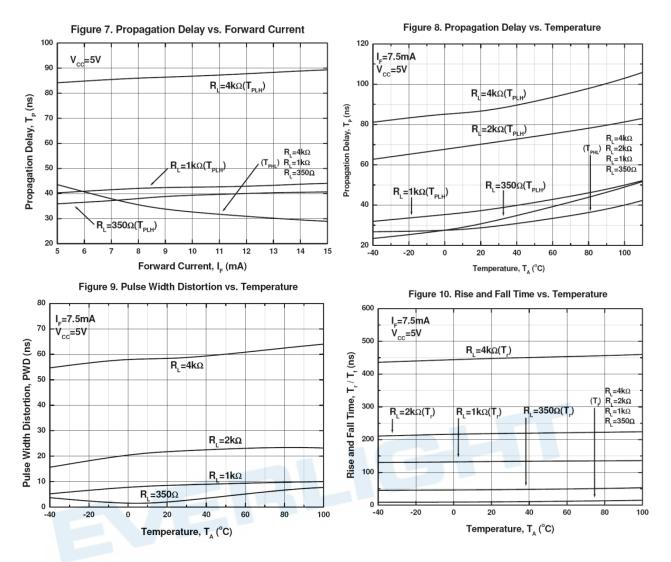
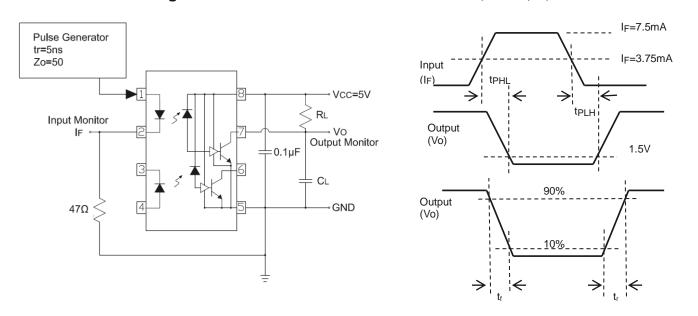


Fig. 11 Test circuit and waveforms for tPHL, tPLH, tr, and tf





lF Vcc=5V 350Ω ⊸ Vo $0.1 \mu F$ **GND VCM** Peak Vсм 0٧ 5V **CM**H Switching Pos. (A), IF=0 Vo Vo(Min) ____ V_O(Max) Switching Pos. (B), IF=7.5mA **VCM** CML 0.5V

Fig. 12 Test circuit Common mode Transient Immunity

Note

- *3 The VCC supply must be bypassed by a 0.1µF capacitor or larger. This can be either a ceramic or solid tantalum capacitor with good high frequency characteristic and should be connected as close as possible to the package VCC and GND pins
- *4. tPLH Propagation delay is measured from the 3.75mA level on the HIGH to LOW transition of the input current pulse to the 1.5 V level on the LOW to HIGH transition of the output voltage pulse.
- *5. tPHL Propagation delay is measured from the 3.75mA level on the LOW to HIGH transition of the input current pulse to the 1.5 V level on the HIGH to LOW transition of the output voltage pulse.
- *6. tr Rise time is measured from the 90% to the 10% levels on the LOW to HIGH transition of the output pulse.
- *7. tf Fall time is measured from the 10% to the 90% levels on the HIGH to LOW transition of the output pulse.
- *8 CMH– The maximum tolerable rate of rise of the common mode voltage to ensure the output will remain in the HIGH state (i.e., VOUT > 2.0V).
- *9 CML— The maximum tolerable rate of rise of the common mode voltage to ensure the output will remain in the LOW output state (i.e., VOUT < 0.8V).



Order Information

Part Number

EL263XY(Z)-V

Note

X = (0 or 1) for EL26 part no.

Y = Lead form option (S, S1, M or none)

Z = Tape and reel option (TA, TB or none).

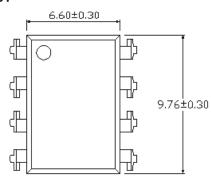
V = VDE (optional)

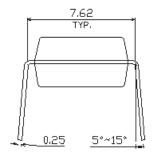
Option	Description	Packing quantity
None	Standard DIP-8	45 units per tube
M	Wide lead bend (0.4 inch spacing)	45 units per tube
S (TA)	Surface mount lead form + TA tape & reel option	1000 units per reel
S (TB)	Surface mount lead form + TB tape & reel option	1000 units per reel
S1 (TA)	Surface mount lead form (low profile) + TA tape & reel option	1000 units per reel
S1 (TB)	Surface mount lead form (low profile) + TB tape & reel option	1000 units per reel
E	VERLIGH	

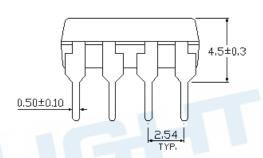


Package Dimension (Dimensions in mm)

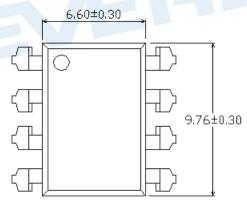
Standard DIP Type

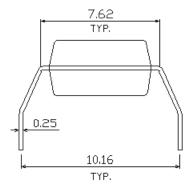


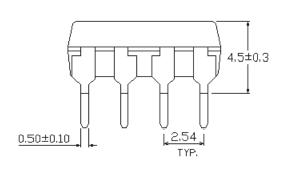




Option M Type

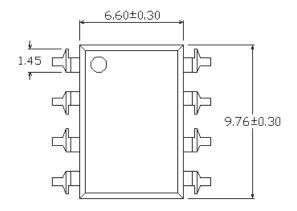


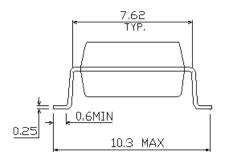


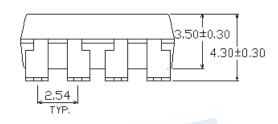




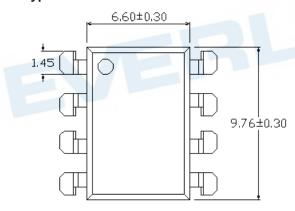
Option S Type

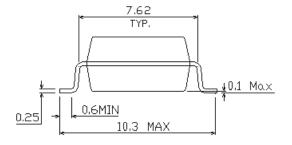


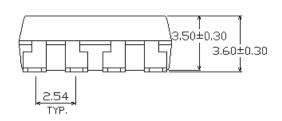




Option S1 Type

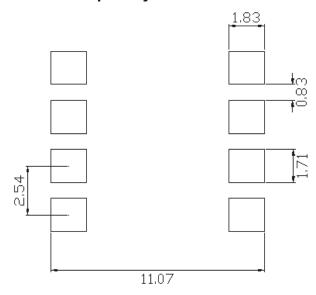








Recommended pad layout for surface mount leadform



Notes.

Suggested pad dimension is just for reference only. Please modify the pad dimension based on individual need.

Device Marking



Notes

T denotes Factory

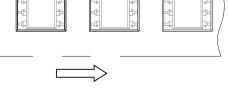
No code : made in China

T : made in Taiwan

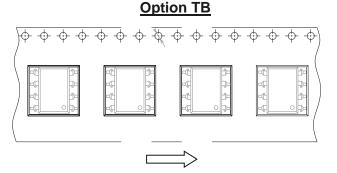
EL denotes EVERLIGHT
2631 denotes Device Number
Y denotes 1 digit Year code
WW denotes 2 digit Week code
V denotes VDE (optional)



Tape & Reel Packing Specifications

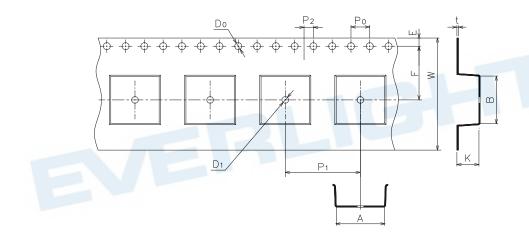


Direction of feed from reel



Direction of feed from reel

Tape dimension



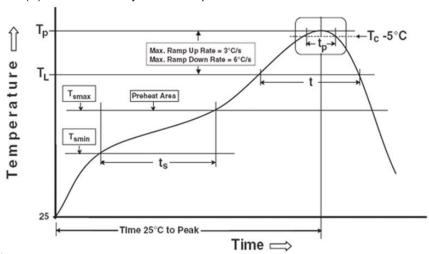
Dimension No.	Α	В	Do	D1	E	F
Dimension(mm)	10.4±0.1	10.0±0.1	1.5+0.1/-0	1.5±0.25	1.75±0.1	7.5±0.1
Dimension No.	Ро	P1	P2	t	w	К
Dimension(mm)	4.0±0.1	12.0±0.1	2.0±0.05	0.4±0.05	16.0±0.3	4.5±0.1



Precautions for Use

1. Soldering Condition

1.1 (A) Maximum Body Case Temperature Profile for evaluation of Reflow Profile



Note: Reference: IPC/JEDEC J-STD-020D

Preheat

Temperature min (T_{smin})

150°C

Temperature max (T_{smax})

200°C

Time $(T_{smin} \text{ to } T_{smax})$ (t_s) 60-120 seconds Average ramp-up rate $(T_{smax} \text{ to } T_p)$ 3°C/second max

Other

Peak Temperature (T_P)

Liquidus Temperature (T_L) 217°C

Time above Liquidus Temperature (t L) 60-100 sec

Time within 5 °C of Actual Peak Temperature: T_P - 5°C 30 s

Ramp- Down Rate from Peak Temperature 6°C /second max.

Camp- Down Nate from Feak femperature 6 C/Second ma

Time 25°C to peak temperature 8 minutes max.

Reflow times 3 times

260°C



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